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MEMC 98-3052 (2512.2) PATENT

10V 0 7 2003 JN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert J. Falster

Art Unit 2814

Serial No. 10/038,084 Filed January 03, 2002 Confirmation No. 7363

For SILICON ON INSULATOR STRUCTURE HAVING A LOW DEFECT DENSITY DEVICE LAYER AND A PROCESS FOR THE PREPARATION THEREOF Examiner Anh D. Mai

November 7, 2003

## **AMENDMENT B**

TO THE COMMISSIONER FOR PATENTS,

SIR:

In response to the Office action dated May 7, 2003, please make the following amendments and consider the following remarks and arguments:

**Amendments to the Claims** are reflected in the listing of claims that begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.